

SYMMETRIC STACK UP STRUCTURE FOR ORGANIC BGA CHIP CARRIERS

- This application claims priority to the provisional patent application entitled,
5 "Symmetric Stack Up Structure For BGA/Flip Chip Products," serial number 60/254438,
filed on December 8, 2000.

BRIEF DESCRIPTION OF THE INVENTION

- The present invention relates generally to the field of semiconductor
10 packaging. More specifically, the present invention relates to an improved structure for
organic ball-grid array (BGA) chip carriers having metal heat sink plates.

BACKGROUND OF THE INVENTION

- One of the popular BGA chip carriers available in the semiconductor
15 packaging industry is an organic substrate utilizing cavity die-attach configuration. This
type of chip carrier is typically constructed with an organic substrate having a multi-layer
structure attached to a metal heat sink plate using an adhesive.

- The organic substrate may be constructed from materials such as Bis-
malesimide triazine epoxy (BT), FR4, polyimide, and polytetrafluoroethylene. The metal
20 heat sink plate (a.k.a. "heatslug") dissipates heat away from the semiconductor die and is
usually made of a metal or metal alloy with relatively high thermal conductivity, such as Cu,
Al, and Cu-W.

- The organic substrate has an opening in the center that forms a die-attach
cavity when the substrate is attached to the metal heat sink plate. A semiconductor die is
25 placed within the die-attach cavity and attached to the metal heat sink plate using a
thermally conductive adhesive such as silver epoxy. The die-attach cavity opening may
typically be a square or a rectangular opening that would be appropriate to accommodate the
particular die being attached to the substrate.

- The semiconductor die is typically placed within the die-attach cavity with
30 its active side facing out so that wirebond wires can form electrical interconnections
between the die and the organic substrate. The wirebond wires connect bonding pads on the
semiconductor die to corresponding bonding pads on the substrate and are typically
ultrasonically bonded to the bonding pads. A glob-top epoxy sealant is then used to
encapsulate the semiconductor die and the wirebond wires.

- One of the concerns associated with chip carriers described above is that the
35 difference in coefficients of thermal expansion (CTE) of the metal heat sink plate and the

organic substrate results in warping of the chip carrier post-assembly. During the high-temperature curing step for the adhesive used to attach the organic substrate to the metal heat sink plate, the organic substrate expands more than the metal heat sink plate. As the adhesive cures, the organic substrate and the metal heat sink plate are fixated in this state where the organic substrate has expanded more than the metal heat sink plate. Upon subsequent cooling of the assembly, the organic substrate contracts more than the metal heat sink plate, causing the chip carrier assembly to warp.

Some examples of the adhesives that may be used to attach the organic substrate to the metal heat sink plate are: epoxy based adhesives, acrylic, and pre-preg. The curing temperatures for these adhesives are typically in the range of 150 - 300 deg. C.

The chip carrier assembly warping poses manufacturability problems because under the current JEDEC standards for electronic packages, a package may not warp more than 0.008 inches. Although, the warping problem could be minimized or eliminated by increasing the thickness of the metal heat sink plate, thereby increasing the chip carrier assemblies' stiffness, it is not practicable because also under the current JEDEC standards, the maximum thickness allowed for metal heat sink plates is only 1.0 mm, which is not sufficient to prevent chip carrier assemblies from warping.

SUMMARY OF THE INVENTION

To address the warping problem with organic cavity die-attach BGA chip carriers, the present invention utilizes a second organic substrate structure (the "supplemental substrate") to counter balance the bending force resulting from the mismatch of CTEs between the main organic substrate (the "primary substrate") and the metal heat sink plate. The supplemental substrate is attached to the metal heat sink plate on the side opposite from the primary substrate resulting in a symmetrically stacked up structure with the metal heat sink plate sandwiched between the two organic substrate structures.

The supplemental substrate is preferably constructed from materials having a CTE that is substantially similar to the CTE of the primary substrate. The supplemental substrate preferably has as many physical characteristics of the primary substrate as possible and may also include a Cu core layer found in the primary substrate to better match the CTE of the primary substrate. More preferably, the supplemental substrate may be constructed from the same organic material as the primary substrate.

The supplemental substrate may also have a hole in the center that mirrors the die-attach cavity in the primary substrate. The hole exposes a portion of the metal heat sink plate for improved heat dissipation. If necessary, supplemental heat dissipating

structures such as metal fins may be attached to the exposed portion of the metal heat sink plate.

Because the supplemental substrate, constructed from the same material as the primary substrate, has a CTE that is substantially similar to that of the primary substrate, the symmetrical stack up structure provides symmetry in the thermal expansion of the structures on the two sides of the metal heat sink plate, thus, preventing the assembly from warping.

BRIEF DESCRIPTION OF THE DRAWINGS

For a better understanding of the invention, reference should be made to the following detailed description taken in conjunction with the accompanying drawings, in which:

Figure 1 illustrates a cross-sectional view of a semiconductor chip carrier having the symmetric structure according to the present invention; and

Figure 2 illustrates a cross-sectional view of another embodiment of a semiconductor chip carrier having the symmetric structure according to the present invention.

The drawings are only schematic and are not to scale.

DETAILED DESCRIPTION OF THE INVENTION

The following detailed description of the present invention is for illustrative purposes and should not be construed to limit the invention to these examples.

In an embodiment of the invention illustrated in **Figure 1**, a cross-section of an organic BGA chip carrier **30** with a cavity die-attach configuration is shown. A multi-layer organic substrate **32**, the primary substrate, having BGA solder balls **70** is attached to one side of a Cu heat sink plate **34**. The primary substrate has internal wiring and it provides the electrical interconnection between the semiconductor die and the next level packaging, typically a printed circuit board, through BGA solder balls **70**.

Primary substrate **32** has a hole which forms a die-attach cavity **38** within which a semiconductor die **40** sits. Semiconductor die **40** is physically attached to the Cu heat sink plate and electrically connected to the primary substrate **32** by wirebond wires **42** and then encapsulated with glob-top epoxy **44**. The primary substrate may be attached to the Cu heat sink plate using adhesives such as epoxy based adhesives, acrylic, or pre-preg. To enhance the adhesion between the organic substrates and the Cu heat sink plate, the Cu surface may be chemically treated to form a layer of black oxide (Cu-SO₄).

On the other side of Cu heat sink plate 34 is attached a supplemental substrate 50 whose primary purpose is a structural one. Supplemental substrate 50 is preferably constructed from a material having a CTE that is substantially similar to the CTE of the primary substrate so that the resulting chip carrier has a symmetry about the Cu heat sink plate, i.e., the Cu heat sink plate is sandwiched between two organic substrates having substantially similar CTEs.

In the resulting symmetrically stacked up structure, the CTE of supplemental substrate 50 is substantially similar to the CTE of the primary substrate. In this structure, the bending force created by the mismatch of CTEs between the primary substrate and the Cu heat sink plate is counterbalanced by the mismatch of CTEs between the supplemental substrate and the Cu heat sink plate. Thus, this symmetry eliminates or substantially minimizes the chip carrier warping problem because the bending forces on each side of the Cu heat sink plate are substantially equal and directed in opposing directions.

The supplemental substrate preferably has as many physical characteristics of the primary substrate as possible to better match the CTE of the primary substrate and may include a Cu core layer commonly found in the primary substrate. More preferably, the supplemental substrate may be constructed from the same organic material as the primary substrate. As with the primary substrate, the supplemental substrate may be attached to the Cu heat sink plate using adhesives such as epoxy based adhesives, acrylic, or pre-preg.

The supplemental substrate may also be provided with a hole 58 to expose a portion of the Cu heat sink plate to improve heat dissipation, if necessary. A set of cooling fins (not shown) or other appropriate supplemental heat dissipation devices may also be attached to the exposed portion of the Cu heat sink to further improve heat dissipation.

It is to be appreciated that although the primary function of the supplemental substrate is a structural one, the supplemental substrate may also be configured and adapted to have other functions. For example, the supplemental substrate structure may be provided with appropriate electrical wiring features, such as signal wiring or ground and signal plane structures to provide the chip carrier with additional interconnection features if necessary.

The invention is applicable to BGA chip carriers in cavity die-attach format having organic substrates constructed from BT as well as other organic materials such as FR4, polyimide, polytetrafluoroethylene, etc. The invention is also applicable to chip carriers having heat sink plates constructed from Cu or other metal or metal alloys such as Al or Cu-W. Furthermore, the invention is applicable to any chip carrier whose heat sink plate has a CTE that is sufficiently different from the CTE of the primary substrate causing the chip carrier to warp.

Figure 2 illustrates another embodiment of the invention, where, the primary substrate **32'** has a Cu core **60**. In this embodiment, supplemental substrate **50'** may also be provided with a Cu core **70**. Supplemental substrate **50'** may also be provided with a Cu-Ni finish layer **52** for device marking purposes. Manufacturer's name, logo, part number, etc.

5 may be marked on the Cu-Ni finish layer.

Many modifications and variations are possible in view of the above teachings. The embodiments were chosen and described in order to best explain the principles of the invention and its practical applications, to thereby enable others skilled in the art to best utilize the invention and various embodiments with various modifications as
10 are suited to the particular use contemplated. It is intended that the scope of the invention be defined by the appended claims and their equivalents.

15

20

25

30

35